

TECHNICAL DATA SHEET High Purity Aluminum Nitride (AIN) Granules

Chemical Analysis

	GS-80	SS-80
Yttrium Oxide (Y ₂ O ₃) - wt%	5	5
Calcium (Ca) - ppm	100-200	< 30
Silicon (Si) - ppm	< 30	< 20
Iron (Fe) - ppm	< 10	< 10

Sizing and Properties

	GS-80	SS-80
Mean Particle Size	80 µm	80 µm
Apparent Density - g/cm ³	0.8-1.0	0.8-1.0
Tap Density - g/cm³	0.9-1.1	0.9-1.1

Description:

GNPGraystar's Aluminum Nitride is a transparent, high purity AlN that exhibits high thermal conductivity (near 320 W/m·K), high electrical insulation properties, high strength, low thermal expansion coefficient and excellent resistance to plasma.

Applications:

GNPGraystar's High Purity Aluminum Nitride (AIN) Fillers are used in the production of IGBT driver boards, semiconductor manufacturing, parts such as etching mask, electrostatic chuck, and heater, in LED heat dissipation boards, in crucibles, and many other applications.

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